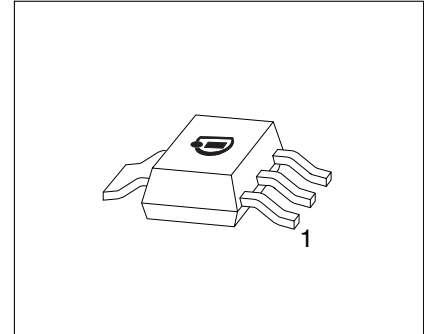




- High-side switch
- Short-circuit protection
- Input protection
- Overtemperature protection with hysteresis
- Overload protection
- Overvoltage protection
- Switching inductive load
- Clamp of negative output voltage with inductive loads
- Undervoltage shutdown
- Maximum current internally limited
- **Electrostatic discharge (ESD)** protection
- Reverse battery protection¹⁾
- AEC qualified
- Green product (RoHS compliant)



PG-SOT-223

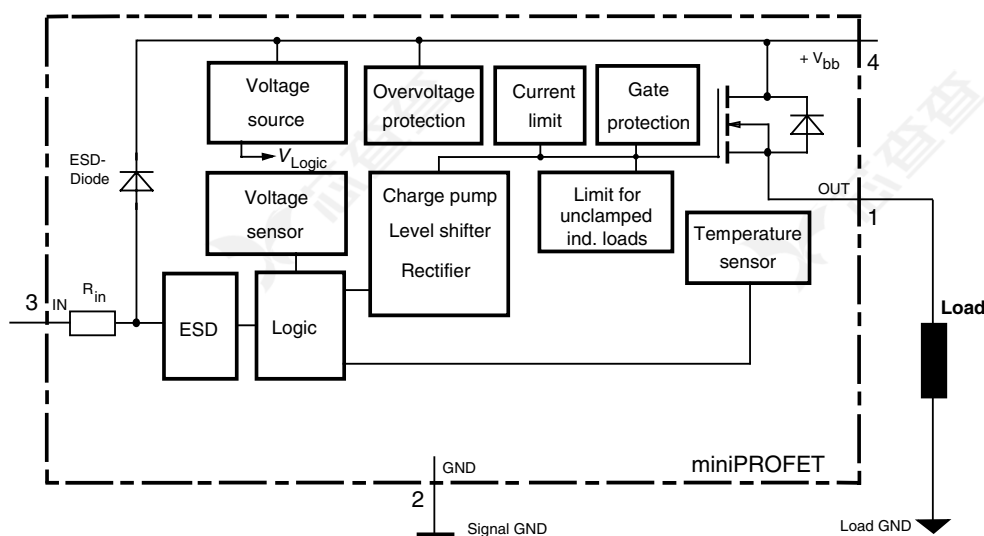
Application

- μ C compatible power switch for 12 V DC grounded loads
- All types of resistive, inductive and capacitive loads
- Replaces electromechanical relays and discrete circuits

General Description

N channel vertical power FET with charge pump, ground referenced CMOS compatible input, monolithically integrated in Smart SIPMOS[®] technology. Fully protected by embedded protection functions.

Blockdiagramm:



¹⁾ With resistor $R_{GND}=150 \Omega$ in GND connection, resistor in series with IN connections reverse load current limited by connected load.


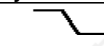
Electrical Characteristics

Parameter and Conditions at $T_j = 25\text{ }^\circ\text{C}$, $V_{bb} = 13.5\text{V}$ unless otherwise specified	Symbol	Values			Unit
		min	typ	max	

Load Switching Capabilities and Characteristics

On-state resistance (pin 4 to 1) $I_L = 0.5\text{ A}$, $V_{in} = \text{high}$	$T_j = 25\text{ }^\circ\text{C}$ $T_j = 150\text{ }^\circ\text{C}$	R_{ON}	-- --	0.16 --	0.2 0.4	Ω
Nominal load current (pin 4 to 1) ⁷⁾ ISO Standard: $V_{ON} = V_{bb} - V_{OUT} = 0.5\text{ V}$ $T_S = 85\text{ }^\circ\text{C}$		$I_{L(ISO)}$	0.7	--	--	A
Turn-on time Turn-off time $R_L = 24\text{ }\Omega$	to 90% V_{OUT} to 10% V_{OUT}	t_{on} t_{off}	-- --	60 60	100 150	μs
Slew rate on 10 to 30% V_{OUT} , $R_L = 24\text{ }\Omega$		dV/dt_{on}	--	2	4	$\text{V}/\mu\text{s}$
Slew rate off 70 to 40% V_{OUT} , $R_L = 24\text{ }\Omega$		$-dV/dt_{off}$	--	2	4	$\text{V}/\mu\text{s}$

Input

Allowable input voltage range, (pin 3 to 2)		V_{IN}	-3.0	--	V_{bb}	V
Input turn-on threshold voltage  $T_j = -40\dots+150\text{ }^\circ\text{C}$		$V_{IN(T+)}$	--	--	3.5	V
Input turn-off threshold voltage  $T_j = -40\dots+150\text{ }^\circ\text{C}$		$V_{IN(T-)}$	1.5	--	--	V
Input threshold hysteresis		$\Delta V_{IN(T)}$	--	0.5	--	V
Off state input current (pin 3) $V_{IN(off)} = 1.2\text{ V}$ $T_j = -40\dots+150\text{ }^\circ\text{C}$		$I_{IN(off)}$	10	--	60	μA
On state input current (pin 3) $V_{IN(on)} = 3.0\text{ V to } V_{bb}$ $T_j = -40\dots+150\text{ }^\circ\text{C}$		$I_{IN(on)}$	10	--	100	μA
Input resistance		R_{IN}	1.5	2.8	3.5	k Ω

⁷⁾ $I_{L(ISO)}$ is limited by current limitation, see $I_{L(SC)}$, next page

Parameter and Conditions at $T_j = 25^\circ\text{C}$, $V_{bb} = 13.5\text{V}$ unless otherwise specified	Symbol	Values			Unit	
		min	typ	max		
Operating Parameters						
Operating voltage ⁸⁾	$T_j = -40\dots+150^\circ\text{C}$	$V_{bb(\text{on})}$	5.0	--	34	V
Undervoltage shutdown	$T_j = -40\dots+150^\circ\text{C}$	$V_{bb(\text{under})}$	3.5	--	5	V
Undervoltage restart	$T_j = -40\dots+25^\circ\text{C}$ $T_j = +150^\circ\text{C}$	$V_{bb(\text{u rst})}$	--	--	6.5 7.0	V
Undervoltage restart of charge pump see diagram page 7		$V_{bb(\text{ucp})}$	--	5.6	7	V
Undervoltage hysteresis $\Delta V_{bb(\text{under})} = V_{bb(\text{u rst})} - V_{bb(\text{under})}$		$\Delta V_{bb(\text{under})}$	--	0.3	--	V
Overvoltage shutdown	$T_j = -40\dots+150^\circ\text{C}$	$V_{bb(\text{over})}$	34	--	42	V
Overvoltage restart	$T_j = -40\dots+150^\circ\text{C}$	$V_{bb(\text{o rst})}$	33	--	--	V
Overvoltage hysteresis	$T_j = -40\dots+150^\circ\text{C}$	$\Delta V_{bb(\text{over})}$	--	0.7	--	V
Standby current (pin 4), $V_{in} = \text{low}$	$T_j = -40\dots+150^\circ\text{C}$	$I_{bb(\text{off})}$	--	10	25	μA
Operating current (pin 2), $V_{in} = 5\text{V}$		I_{GND}	--	1	1.6	mA
leakage current (pin 1) $V_{in} = \text{low}$	$T_j = -40\dots+25^\circ\text{C}$ $T_j = 150^\circ\text{C}$	$I_{L(\text{off})}$	--	2	5 7	μA

Protection Functions

Current limit (pin 4 to 1) $V_{bb} = 20\text{V}$	$T_j = 25^\circ\text{C}$ $T_j = -40\dots+150^\circ\text{C}$	$I_L(\text{SC})$	0.7 0.7	1.5 --	2 2.4	A
Overvoltage protection $I_{bb}=4\text{mA}$	$T_j = -40\dots+150^\circ\text{C}$	$V_{bb(\text{AZ})}$	41	--	--	V
Output clamp (ind. load switch off) at $V_{\text{OUT}}=V_{bb}-V_{\text{ON}(\text{CL})}$, $I_{bb} = 4\text{mA}$		$V_{\text{ON}(\text{CL})}$	41	47	--	V
Thermal overload trip temperature		T_{jt}	150	--	--	$^\circ\text{C}$
Thermal hysteresis		ΔT_{jt}	--	10	--	K
Inductive load switch-off energy dissipation ⁹⁾ $T_{j \text{ Start}} = 150^\circ\text{C}$, single pulse, $I_L = 0.5\text{A}$, $V_{bb} = 12\text{V}$ (not tested, specified by design)		E_{AS}	--	--	0.5	J
Reverse battery (pin 4 to 2) ¹⁰⁾ (not tested, specified by design)		$-V_{bb}$	--	--	30	V

⁸⁾ At supply voltage increase up to $V_{bb}=5.6\text{V}$ typ without charge pump, $V_{\text{OUT}} \approx V_{bb} - 2\text{V}$

⁹⁾ While demagnetizing load inductance, dissipated energy in PROFET is $E_{\text{AS}} = \int V_{\text{ON}(\text{CL})} \cdot i_L(t) dt$, approx.

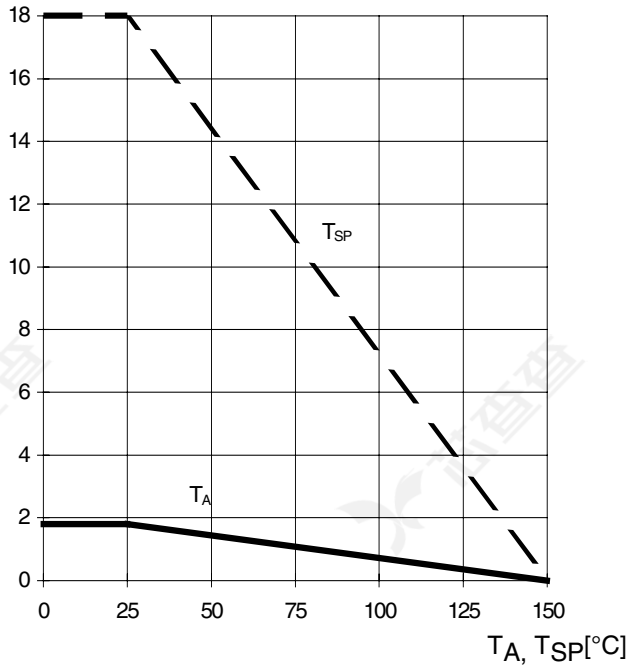
$$E_{\text{AS}} = \frac{1}{2} \cdot L \cdot I_L^2 \cdot \left(\frac{V_{\text{ON}(\text{CL})}}{V_{\text{ON}(\text{CL})} - V_{bb}} \right)$$

¹⁰⁾ Requires $150\ \Omega$ resistor in GND connection. Reverse load current (through intrinsic drain-source diode) is normally limited by the connected load.

Max. allowable power dissipation

$$P_{tot} = f(T_A, T_{SP})$$

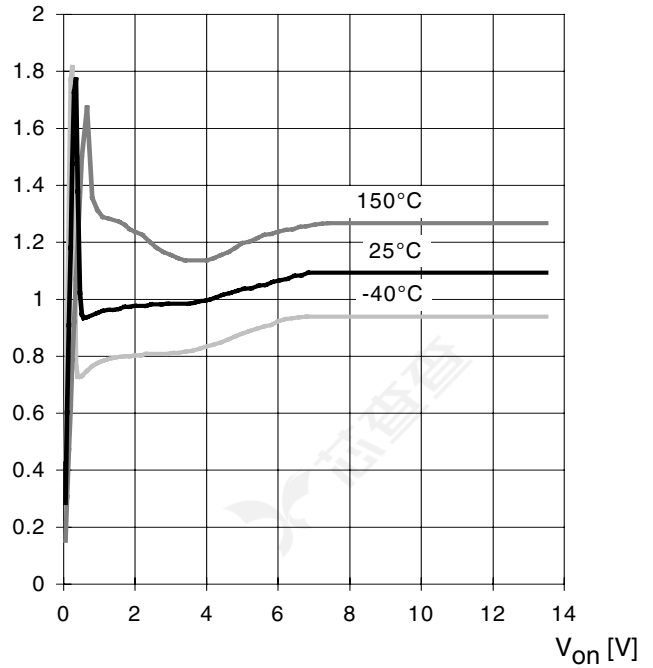
P_{tot} [W]



Current limit characteristic

$$I_{L(SC)} = f(V_{on}); (V_{on} \text{ see testcircuit})$$

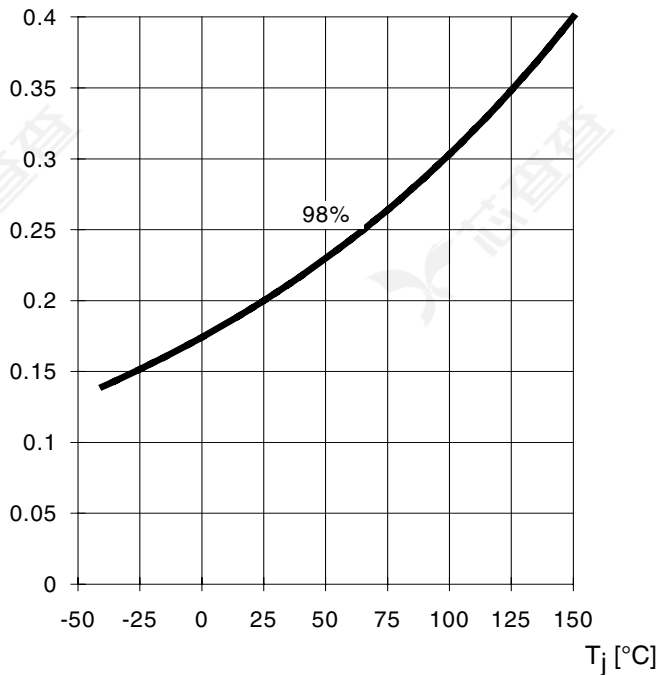
$I_{L(SC)}$ [A]



On state resistance (Vbb-pin to OUT-pin)

$$R_{ON} = f(T_j); V_{bb} = 13.5 \text{ V}; I_L = 0.5 \text{ A}$$

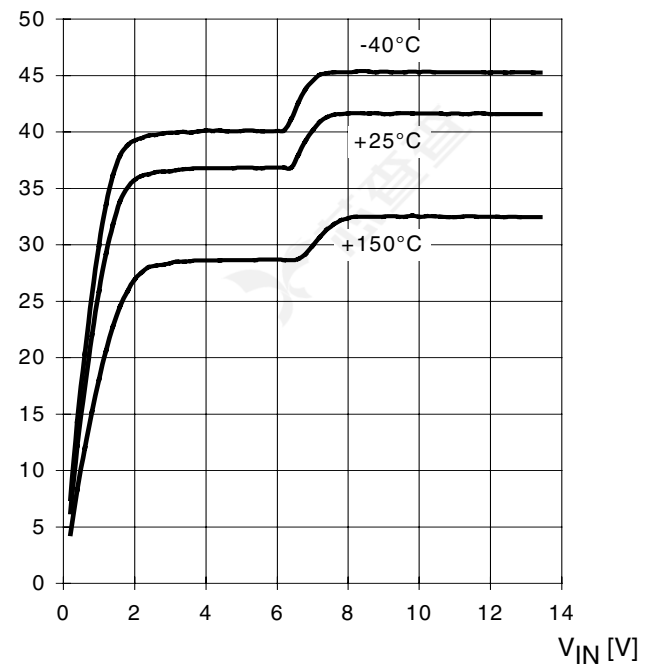
R_{ON} [Ω]



Typ. input current

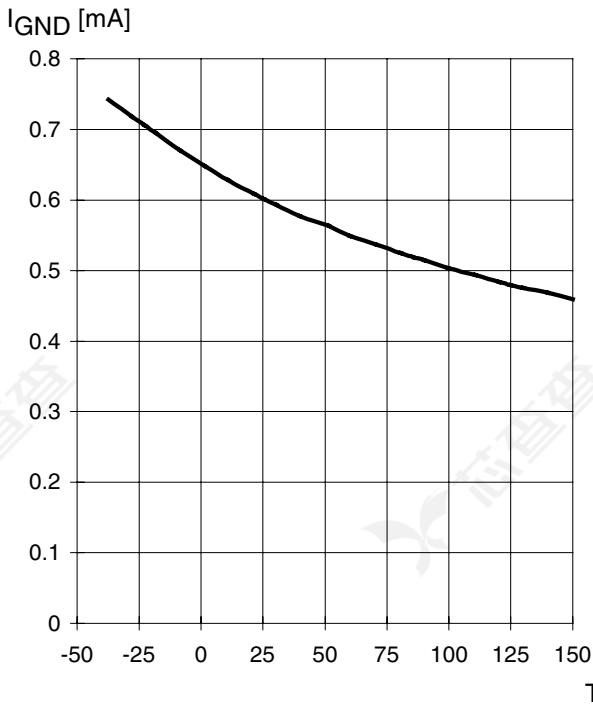
$$I_{IN} = f(V_{IN}); V_{bb} = 13.5 \text{ V}$$

I_{IN} [μA]



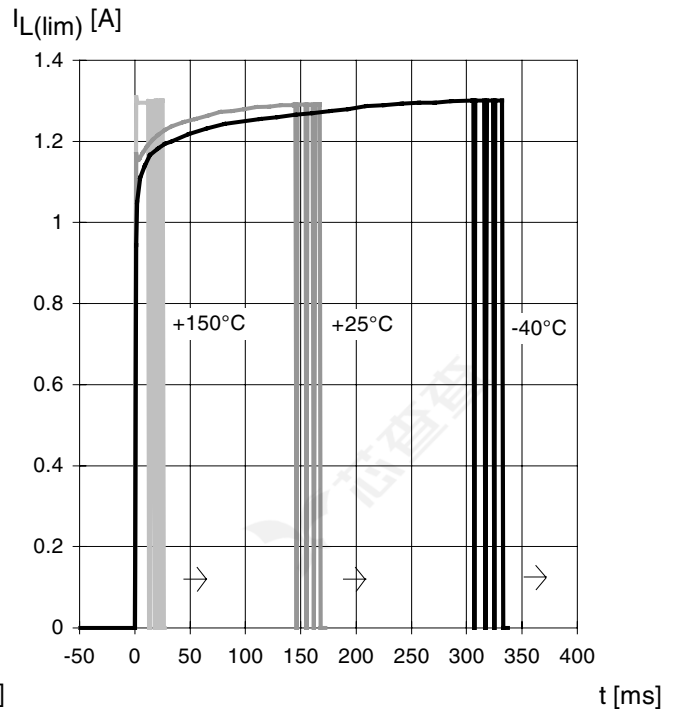
Typ. operating current

$I_{GND} = f(T_j)$; $V_{bb} = 13,5\text{ V}$; $V_{IN} = \text{high}$



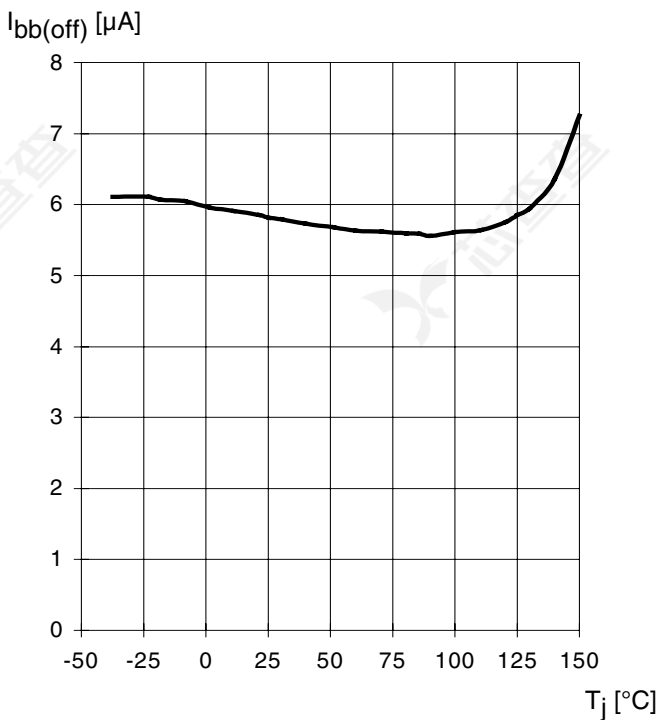
Typ. overload current

$I_{L(\text{lim})} = f(t)$; $V_{bb} = 13,5\text{ V}$, no heatsink, Param.: $T_{j\text{start}}$



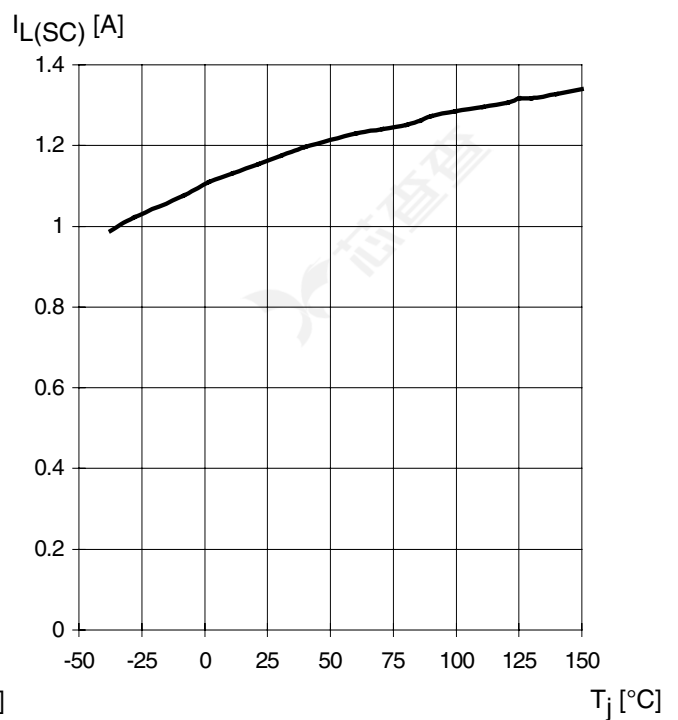
Typ. standby current

$I_{bb(\text{off})} = f(T_j)$; $V_{bb} = 13,5\text{ V}$; $V_{IN} = \text{low}$



Short circuit current

$I_{L(\text{SC})} = f(T_j)$; $V_{bb} = 13,5\text{ V}$



Typ. input turn on voltage threshold
 $V_{IN(T+)} = f(T_j)$;

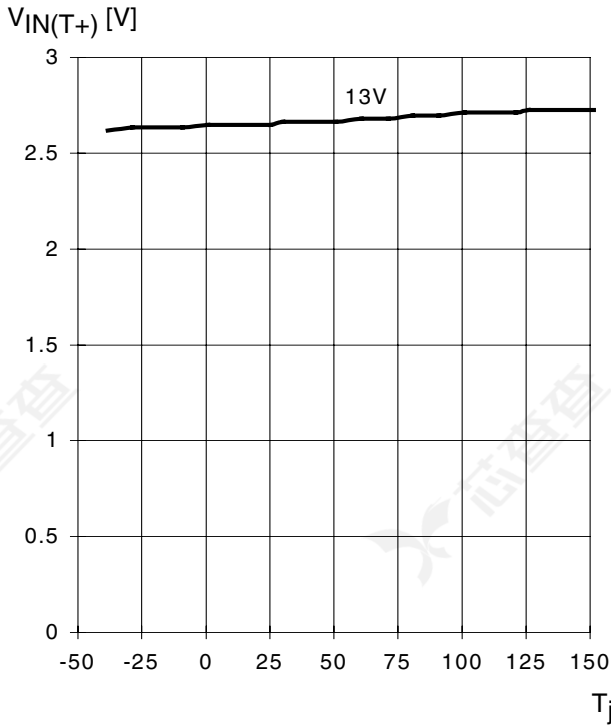
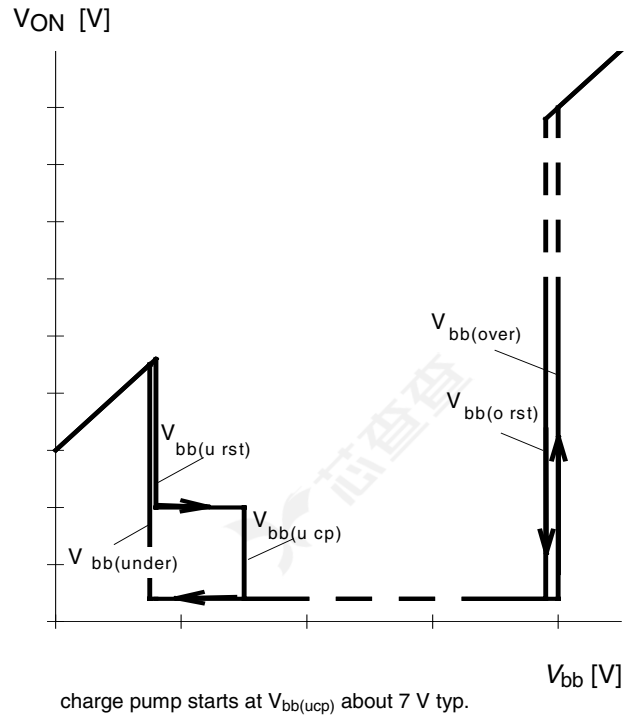
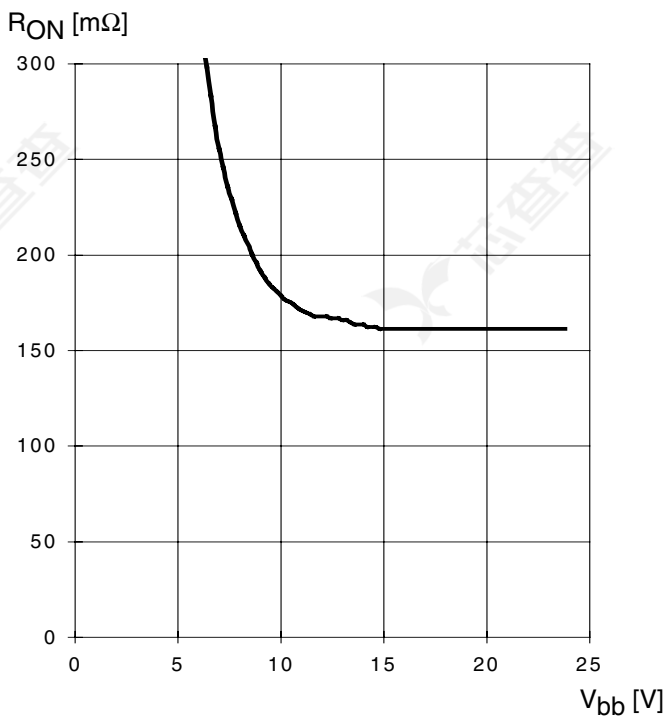


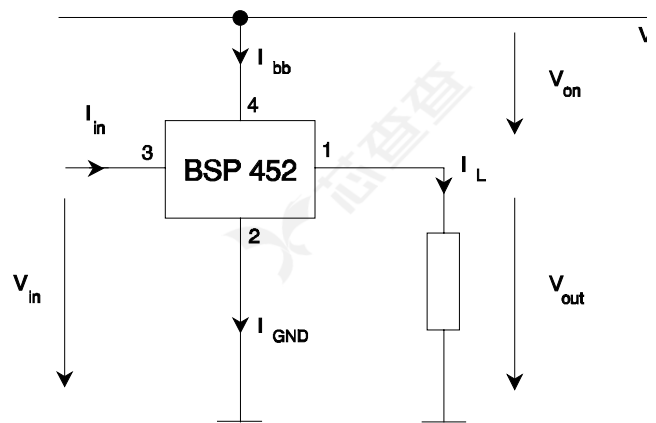
Figure 6: Undervoltage restart of charge pump



Typ. on-state resistance (V_{bb}-Pin to Out-Pin)
 $R_{ON} = f(V_{bb}, I_L)$; $I_L = 0.5A$, $T_j = 25^{\circ}C$



Test circuit



Revision History

Version	Date	Changes
1.0	2007-05-25	Creation of the green datasheet. First page : Adding the green logo and the AEC qualified Adding the bullet AEC qualified and the RoHS compliant features Package page Modification of the package to be green.

Edition 2007-05-25

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